

I-V Characteristic of a pn Diode

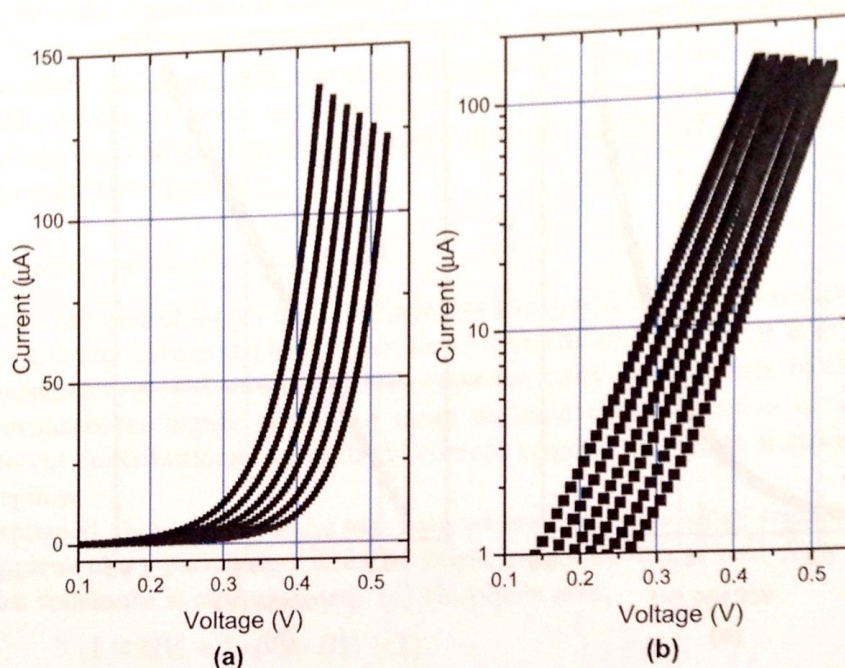


Figure 3. I-V pairs taken at six different temperatures (20.7, 29.7, 39.3, 47.8, 57.2 and 66.3 °C, from right to left), in linear scale (a) and in log₁₀ scale (b) of the currents; it is evident the alignment of the experimental points, suggesting the exponential dependence of I on V .

applying to the series diode- R the variable signal of a digital-to-analog channel (DAC) of the NI6221 board. The control of the thermal cycle and of the data taking is programmed realizing a LabVIEW virtual instrument. Initially, a set of temperatures is selected by the operator. After that the controlled thermal cycles operate until the value of each T is stable into few tenths of °C. The couples $[V, I]$ are saved in a file and are labelled with the temperature measured just before and just after the voltage scan. The difference of two readings of the temperature is ever less than 0.5 °C in absolute value, the sign being dependent on the direction of the last heat flux cycle. So we can evaluate that the value of the diode temperature is known with a precision of 0.2 °C on average.

4. Results and Discussion

4.1. Shockley model

Fig. 3 shows a set of $I-V$ curves taken at different temperature, plotted both in linear and logarithmic scale: it is evident in the right panel the alignment of the experimental points, which is so much better for the higher temperatures and at the higher value of V . The entire set of data required a time of less than ten minutes so that the measures could be done in a standard lab session of 2-3 hours leaving time for a preliminary data analysis and a possible reiteration of the data collection.

The linearity of the experimental $I-V$ characteristic in the logarithmic current scale reported in Fig. 3b indicates, at glance, the region where it is likely an